



Ultra Low Capacitance ESD Protection Diode

DESCRIPTION

RCLAMP0521P-N a low- capacitance Transient Voltage Suppressor (TVS) designed to provide electrostatic discharge (ESD) protection for high-speed data interfaces. With typical capacitance of 0.5pF RCLAMP0521P-Ndesigned to protect parasitic-sensitive systems against over-voltage and over-current transient events. It complies with IEC 61000-4-2 (ESD), Level 4 (±15kV air, ±8kV contact discharge), IEC 61000-4-4 (electrical fast transient - EFT) (40A, 5/50 ns), very fast charged device model (CDM) ESD and cable discharge event (CDE), etc.

RCLAMP0521P-N ultra-small 0402 package. Each RCLAMP0521P-N device can protect one high-speed data line. It offers system designers flexibility to protect single data line where space is a premium concern. The combined features of low capacitance, ultra-small size and high ESD robustness make RCLAMP0521P-N ideal for high-speed data port and high-frequency line applications, such as cellular phones and HD visual devices.

FEATURES

IEC 61000-4-4 (EFT) 40A (5/50 ns) Cable Discharge Event (CDE)

- ♦Package optimized for high-speed lines
- ♦ Ultra-small package (1.0mm×0.6mm×0.5mm)
- ♦Protects one data, control line
- ♦Low capacitance: 0.5pF (Typical)
- ♦Low leakage current
- ♦Low clamping voltage

MACHANICAL DATA

- ⇒Flammability Rating: UL 94V-0
- ♦ Packaging: Tape and Reel
- ♦High temperature soldering guaranteed: 260°C/10s
- ♦Reel size: 7 inch

ORDERING INFORMATION

→ Package: 0402→ Marking: N

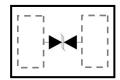
→ Material: Halogen free→ Packing: Tape & Reel

♦ Quantity per reel: 10,000pcs

APPLICATIONS

- ♦ Serial ATA
- ♦ Desktops, Servers and Notebooks
- ♦ Cellular Phones
- ♦MDDI Ports
- ♦USB Data Line Protection
- ♦Display Ports
- ♦ Digital Visual Interfaces (DVI)

PIN CONFIGURATION



PACKAGE OUTLINE





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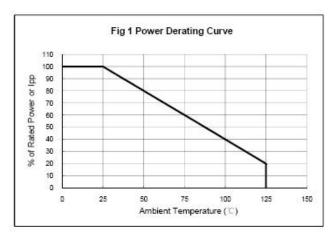
ABSOLUTE MAXIMUM RATING							
Symbol	Parameter	Value	Units				
V _{ESD}	ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	±20 ±20	kV				
P _{PP}	Peak Pulse Power (8/20µs)	100	W				
T _{OPT}	T _{OPT} Operating Temperature		°C				
T _{STG}	Storage Temperature	-55~150	°C				

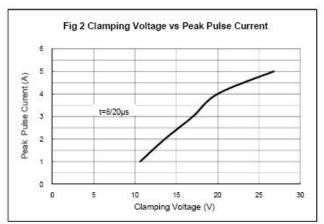
ELECTRI	ELECTRICAL CHARACTERISTICS (Tamb=25°C)								
Symbol	Parameter	Test Condition	Min	Тур	Max	Units			
V_{RWM}	Reverse Working Voltage				5.0	V			
V_{BR}	Reverse Breakdown Voltage	I _T = 1mA	6.0			V			
I _R	Reverse Leakage Current	V _{RWM} = 5V			100	nA			
V _C	Clamping Voltage	$I_{PP} = 1A, t_p = 8/20 \mu s$			13	V			
		$I_{PP} = 4A, t_p = 8/20 \mu s$			25	V			
CJ	Junction Capacitance	V _R = 0V, f = 1MHz		0.5		pF			

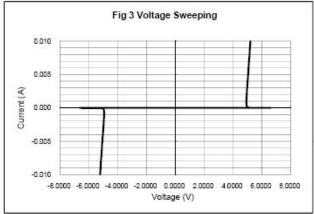


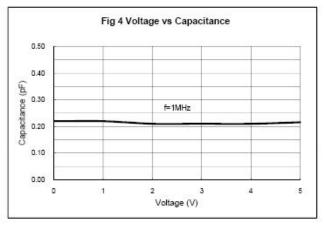
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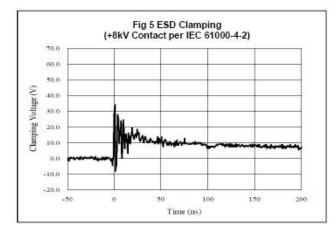
ELECTRICAL CHARACTERISTICS CURVE

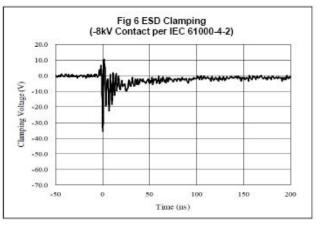








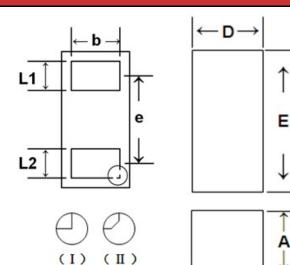






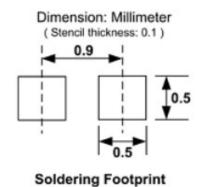
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0402 PACKAGE OUTLINE DIMENSIONS



NOTE: ALL DIMENSIONS IN MM

	MIN	NOM	MAX
D	0.55	0.60	0.65
Е	0.95	1.00	1.05
L1	0.20	0.25	0.30
L2	0.20	0.25	0.30
Α	0.45	0.50	0.55
b	0.45	0.50	0.55
е		0.64BSC	



单击下面可查看定价,库存,交付和生命周期等信息

<u>>>KUU(永裕泰)</u>